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Alessandro Fantoni, Manuela Vieira, and Yuri Vygranenko

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Miguel Fernandes, Manuela Vieira, and Rodrigo Martins

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Jeff Hsin Chang, Tsu Chiang Chuang, Yuri Vygranenko, Denis Striakhilev, Kyung Ho Kim, Arokia Nathan, Gregory Heiler, and Timothy Tredwell
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Kyung Ho Kim, Yuriy Vygranenko, Mark Bedzyk, Jeff Hsin Chang, Tsu Chiang Chuang, Denis Striakhilev, Arokia Nathan, Gregory Heiler, and Timothy Tredwell

POSTER SESSION: ELECTRONICS AND FLEXIBLE SUBSTRATES

Hot-Wire Deposited Nanocrystalline Silicon TFTs on Plastic Substrates

Farhad Taghibakhsh, Michael M. Adachi, and Karim S. Karim

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Growth and Electronic Properties in Hot Wire Deposited Nanocrystalline Si Solar Cells

Kamal Muthukrishnan, Vikram Dalal, and Max Noack

Evolution of Structural and Electronic Properties in Boron-Doped Nanocrystalline Silicon Thin Films

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